

Supporting information for

**Fabrication and design of new redox active azure A/3D graphene aerogel and
conductive trypan blue–nickel MOF nanosheet array electrodes for an
asymmetric supercapattery**

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Figure and Table Captions

Fig. S1. UV-vis absorption of (a) pure Az, GO, Az/GO and (b) Try, Ni₃(Cl)₂(OH)₄ and Try-Ni-MOF aqueous solutions.

Fig. S2. UV-vis. absorption spectra of (a) pure azure A and Az/GA and (b) pure trypan blue and Try-Ni-MOF in 3.0 M KOH solution using three electrode cell setup after completing 500 galvanostatic charge-discharge cycles, respectively.

Fig. S3. XRD patterns of (a) GO, GA, and Az–GA and (b) Try, Ni₃Cl₂(OH)₄, and the Try–Ni-MOF.

Fig. S4. SEM images of GO.

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Fig. S9. TGA curves of (a) GO, GA and Az-GA and (b) Ni₃Cl₂(OH)₄ and Try-Ni-MOF samples in air at a heating rate of 5 °C min⁻¹.

Fig. S10. Suggested mechanism for electrochemical oxidation of (A) Az to B, C or D compounds.

Fig. S11. (a) CVs of the Az-GA electrodes with different azure A to GO ratios from 0.04 to 1 wt% at scan rate of 10 mV s⁻¹ and (b) change in specific capacitance as a function of the wt% azure A to GO ratios for Az-GA/NF electrodes.

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Fig. S14. (a and c) the voltammetric charge (*c*) versus scan rate (*v*^{-1/2}) and (b and d) 1/*c*(*v*) versus *v*^{1/2} plots for Az-GA/NF and Try-Ni-MOF/NF electrode, according to Trasatti method.

Fig. S15. (a, d) GCD of the GA/NF and Ni₃Cl₂(OH)₄/NF electrodes at different current densities in an aqueous 3.0 M KOH electrolyte, (b, e) long-term cycling stability of the GA/NF, Az-GA/NF, Ni₃Cl₂(OH)₄/NF, and Try-Ni-MOF/NF electrodes over 5000 cycles at a current density of 10 A g⁻¹ in an aqueous 3.0 M KOH electrolyte, and (c, f) Bode plots (log |*Z*| vs. log frequency and phase angle vs. log frequency) for the GA/NF, Az-GA/NF, Ni₃Cl₂(OH)₄/NF, and Try-Ni-MOF/NF electrodes at a frequency range from 100 KHz to 10 mHz, respectively.

Fig. S16. Equivalent circuit models used to fit the experimental EIS data of the (a) GA/NF and Az-GA/NF and (b) Ni₃Cl₂(OH)₄/NF and Try-Ni-MOF/NF electrodes in a three-electrode system and in an aqueous 3.0 M KOH electrolyte, respectively.

Fig. S17. (a) Az-GA (negative pole) and Try-Ni-MOF (positive pole) electrodes measured at a scan rate of 10 mV s^{-1} in three-electrode configurations, (b) CV curves of the Az-GA//Try-Ni-MOF asymmetric device at different potential windows 10 mV s^{-1} , (c) GCDs of a Az-GA//Try-Ni-MOF asymmetric device at different potential windows, and (d) specific capacitances of Az-GA//Try-Ni-MOF asymmetric device at various current densities.

Table S1. The d-spacing and crystallite size of GO, GA, Az-GA, $\text{Ni}_3\text{Cl}_2(\text{OH})_4$, and Try-Ni-MOF.

Table S2. Comparison of the electrochemical performances of the Az-GA electrode with other anode electrode reported literatures.

Table S3. Comparison of the electrochemical performances of the Try-Ni-MOF electrode with other cathode electrode reported literatures.

Table S4. Values of equivalent circuit parameters for the GA and Az-GA electrodes.

Table S5. Values of equivalent circuit parameters for the $\text{Ni}_3\text{Cl}_2(\text{OH})_4$ and Try-Ni-MOF electrodes.

Table S6. Comparison of the electrochemical performances of the Az-GA//Try-Ni-MOF device with other devices.

Videos S1



Films.m4v



Film 2.m4v

Characterization of materials

Bragg equation: $n\lambda = 2d \sin(\theta)$

where, n is the order of reflection and can be small integers (number of crystal pages), λ is the wavelength of the X-ray that moves the electron or neutron, d is the empty space between atoms, θ is the angle at which the reflected beams have the greatest amplitude with respect to the initial beams.

Scherrer equation: $D = K\lambda/(B \cos\theta)$

Where D is the mean size of the ordered (crystalline) domains, K is a dimensionless shape factor, with a value close to unity (about 0.9), λ is the X-ray wavelength, β is the line broadening at half the maximum intensity (FWHM), after subtracting the instrumental line broadening, in radians, θ is the Bragg angle.

Bragg equation: $n\lambda = 2d \sin(\theta)$

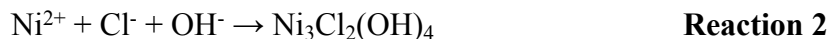
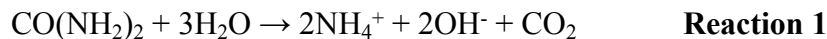
where, n is the order of reflection and can be small integers (number of crystal pages), λ is the wavelength of the X-ray that moves the electron or neutron, d is the empty space between atoms, θ is the angle at which the reflected beams have the greatest amplitude with respect to the initial beams.

Scherrer equation: $D = K\lambda / (\beta \cos\theta)$

Where D is the mean size of the ordered (crystalline) domains, K is a dimensionless shape factor, with a value close to unity (about 0.9), λ is the X-ray wavelength, β is the line broadening at half the maximum intensity (FWHM), after subtracting the instrumental line broadening, in radians, θ is the Bragg angle.

Reactions:

The urea was hydrolyzed into NH_4^+ , OH^- and CO_2 during the hydrothermal process (**Reaction 1**). Then, the resulting NH_4^+ , OH^- reacted with NiCl_2 to formed porous $\text{Ni}_3\text{Cl}_2(\text{OH})_4$ nanosheets (**Reaction 2**). According to the **Reaction 3**, it can be noted that the pseudocapacitive behavior of the compound is mainly attributed to the oxidation and reduction properties of Ni^{2+} and Ni^{3+} . The CVs (**Fig. S12**) show the redox behavior of $\text{Ni}_3\text{Cl}_2(\text{OH})_4/\text{NF}$ electrode and reduction of Ni^{2+} .



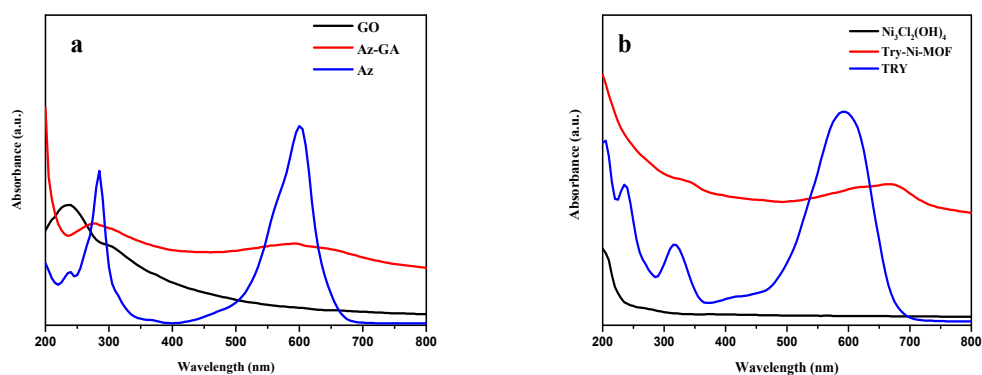


Fig. S1. UV-vis absorption of (a) pure Az, GO, Az/GO and (b) Try, $\text{Ni}_3(\text{Cl})_2(\text{OH})_4$ and Try-Ni-MOF aqueous solutions.

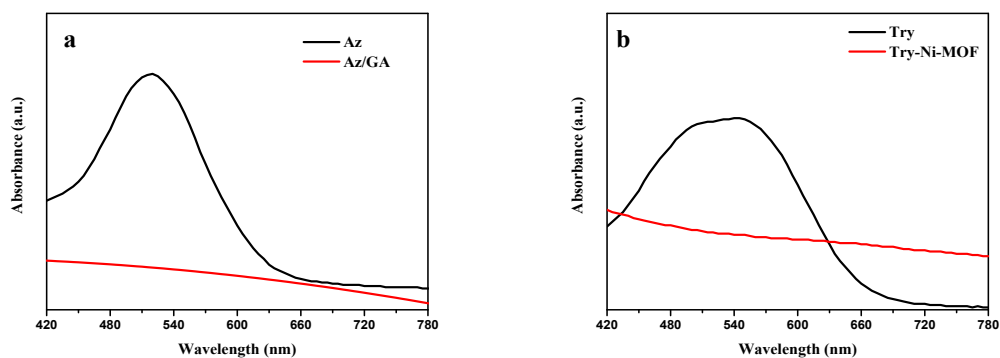


Fig. S2. UV-vis. absorption spectra of (a) pure azure A and Az/GA and (b) pure trypan blue and Try-Ni-MOF in 3.0 M KOH solution using three electrode cell setup after completing 500 galvanostatic charge-discharge cycles, respectively.

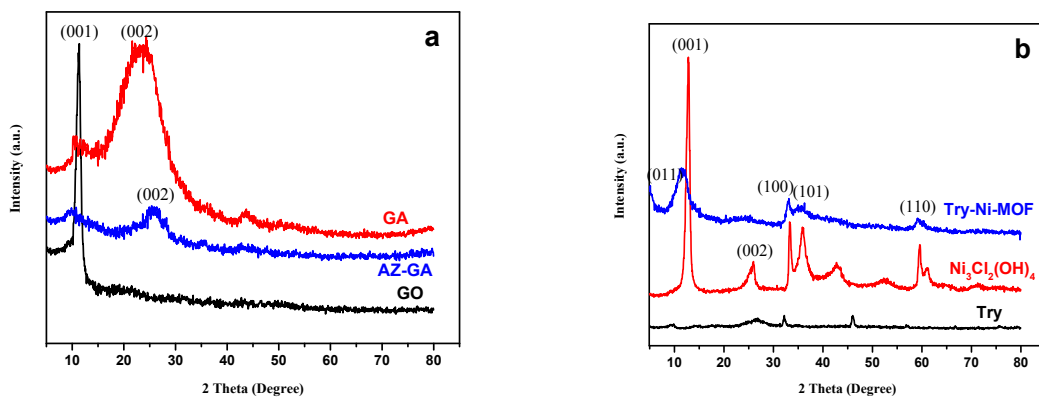


Fig. S3. XRD patterns of (a) GO, GA, and Az-GA and (b) Try, $\text{Ni}_3\text{Cl}_2(\text{OH})_4$, and the Try-Ni-MOF.

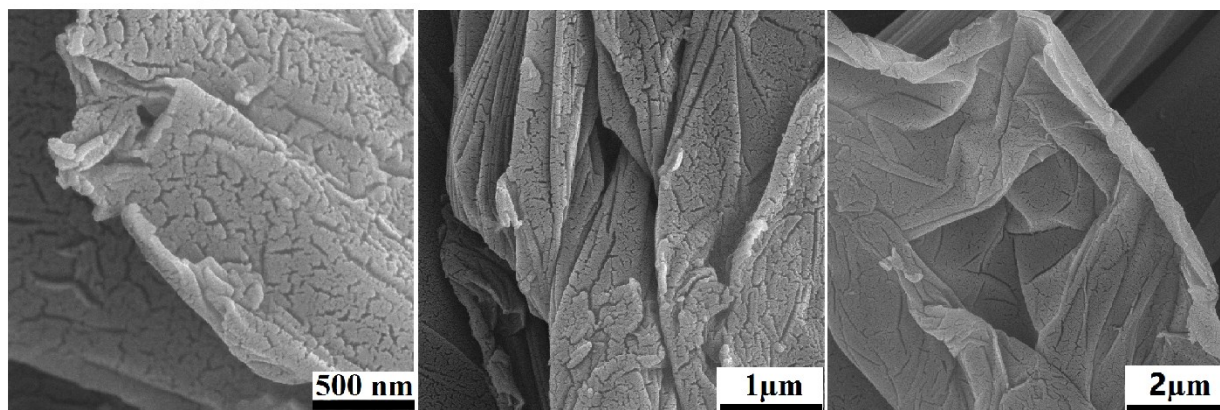


Fig. S4. SEM images of GO

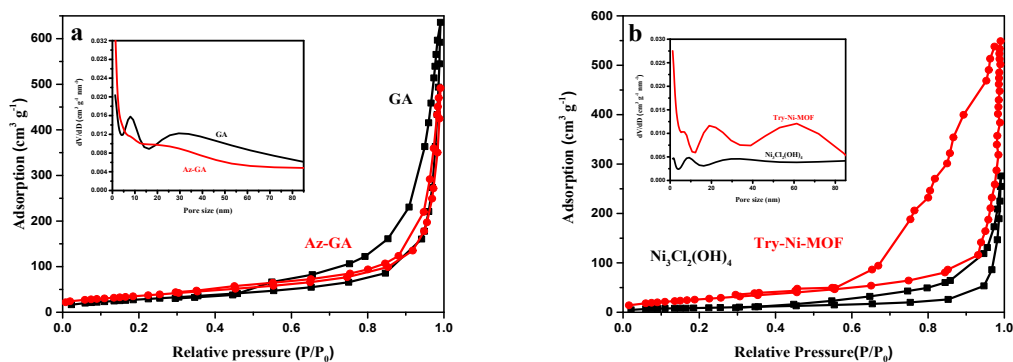


Fig. S5. N_2 adsorption/desorption isotherms of the (a) GA and Az-GA, and (b) $\text{Ni}_3\text{Cl}_2(\text{OH})_4$ and Try-Ni-MOF samples. The insets are BJH pore size distribution curves.

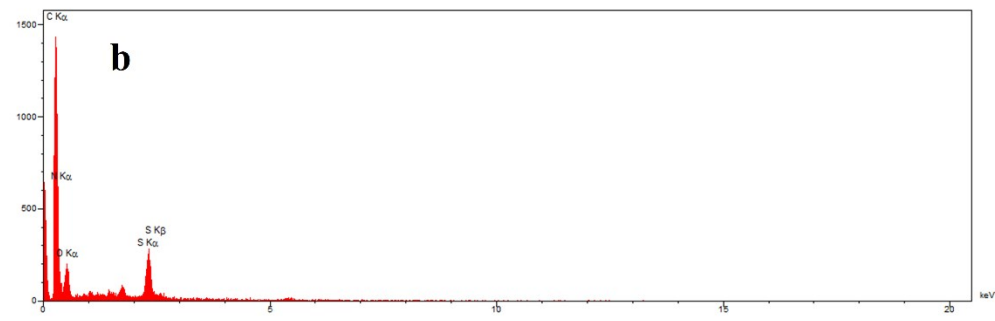
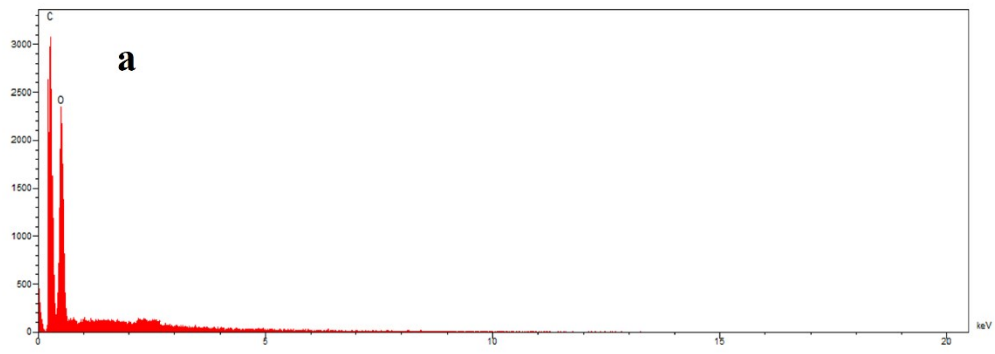
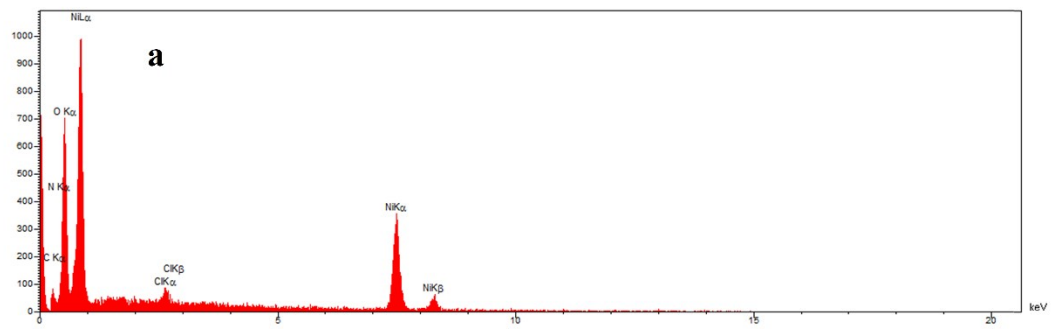


Fig. S6. EDS spectra of the (a) GO and (b) Az-GA



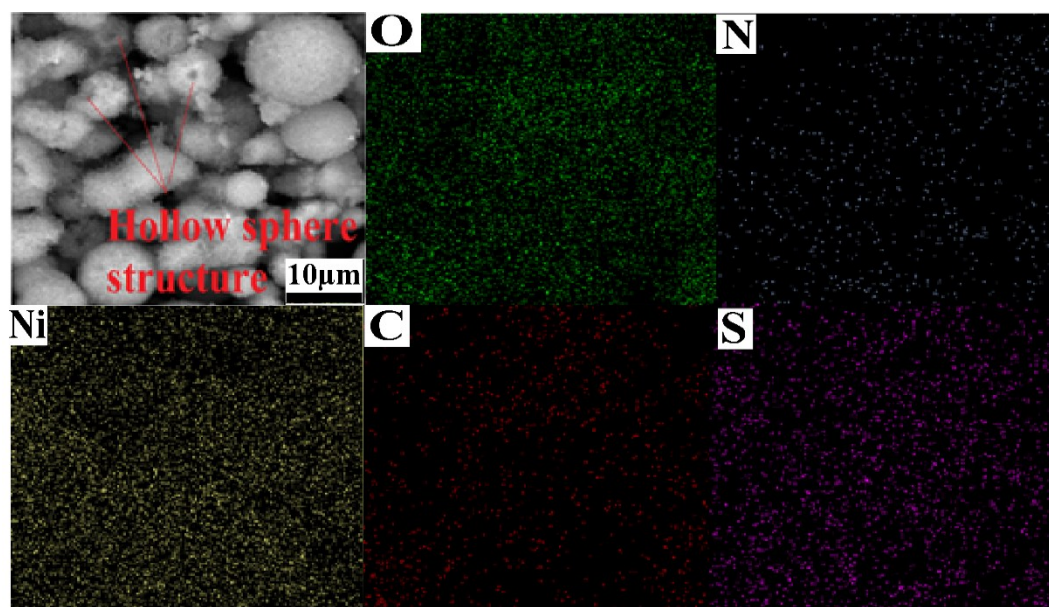
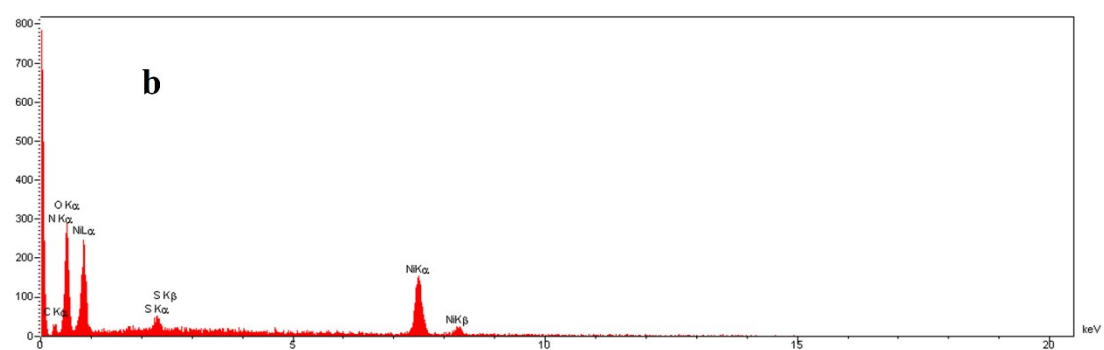
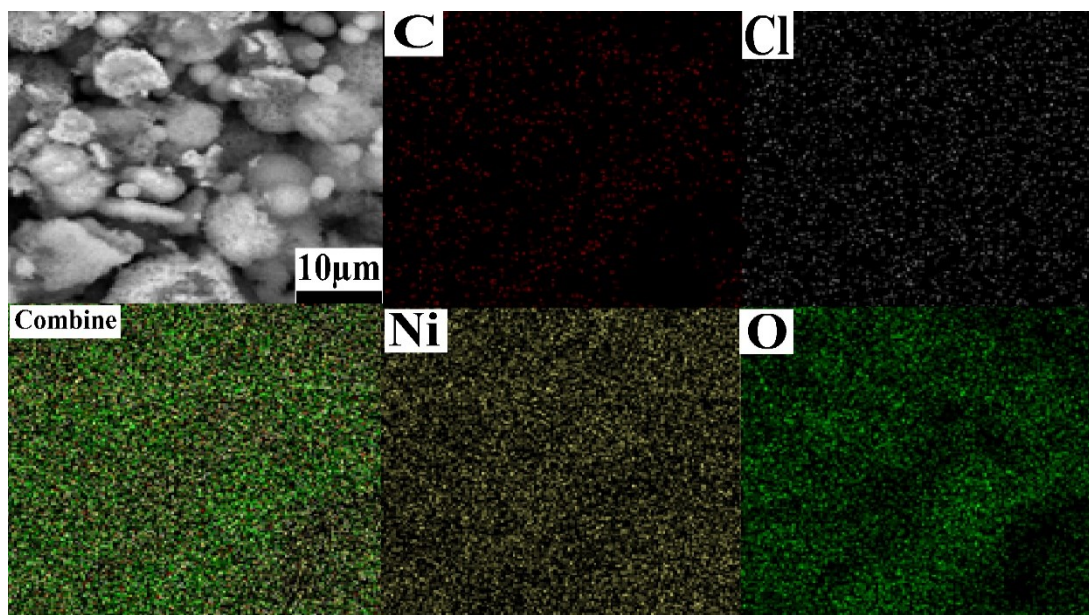


Fig. S7. EDS spectra and mapping of the (a) $\text{Ni}_3\text{Cl}_2(\text{OH})_4$ and (b) Try-Ni-MOF.

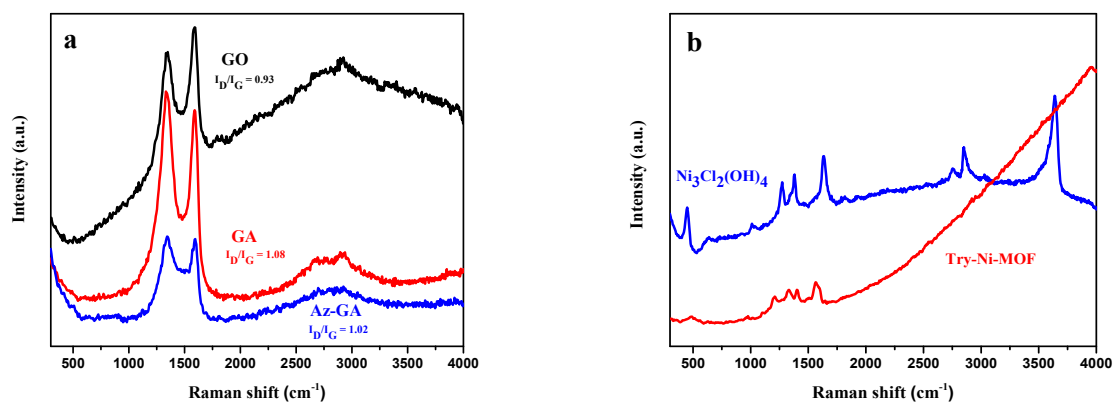


Fig. S8. Raman spectra of a) GO, GA and AZ-GA and b) $\text{Ni}_3\text{Cl}_2(\text{OH})_4$ and Try-Ni-MOF samples.

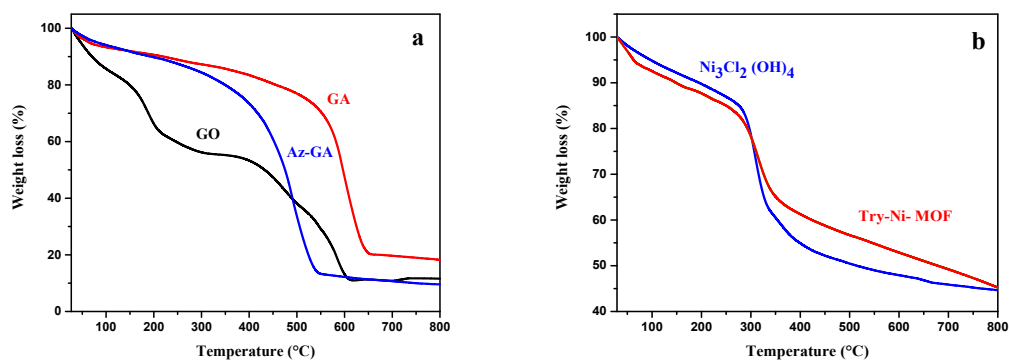


Fig. S9. TGA curves of (a) GO, GA and AZ-GA and (b) $\text{Ni}_3\text{Cl}_2(\text{OH})_4$ and Try-Ni-MOF samples in air at a heating rate of $5\text{ }^{\circ}\text{C min}^{-1}$.

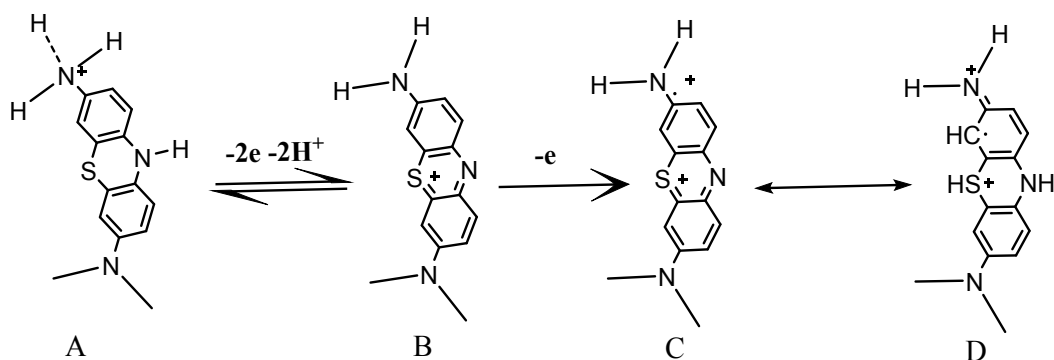


Fig. S10. Suggested mechanism for electrochemical oxidation of (A) Az to B, C or D compounds.

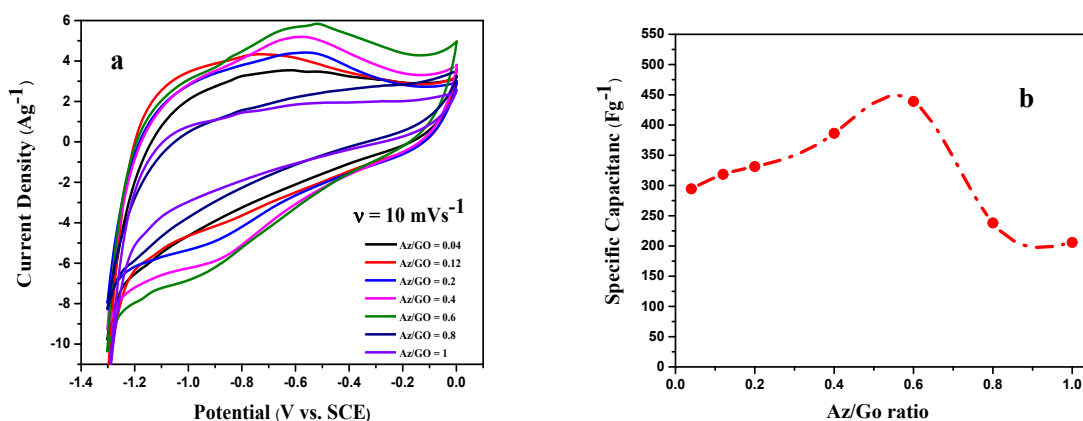


Fig. S11. (a) CVs of the Az-GA electrodes with different azure A to GO ratios from 0.04 to 1 wt% at scan rate of 10 mV s^{-1} and (b) change in specific capacitance as a function of the wt% azure A to GO ratios for Az-GA/NF electrodes.

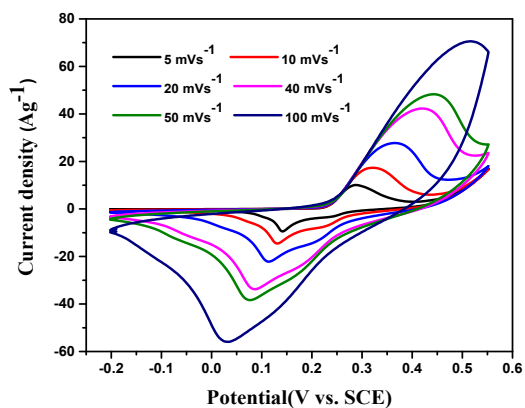


Fig. S12. CVs of $\text{Ni}_3\text{Cl}_2(\text{OH})_4/\text{NF}$ electrode in three-electrode cell setup in aqueous 3.0 m KOH electrolyte at various scan rates from 5 to 100 mV s^{-1} .

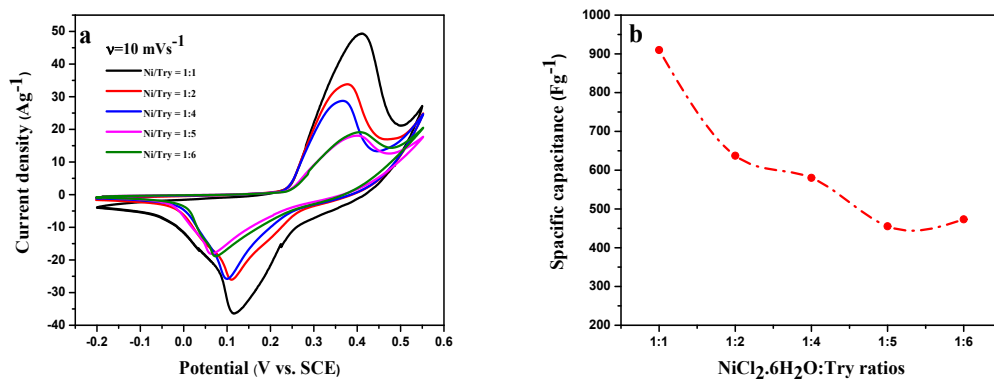


Fig. S13. (a) CVs of the Try-Ni-MOF electrodes with different NiCl₂·6H₂O to trypan blue ratios (1:1, 1:2, 1:4, 1:5, and 1:6) at scan rate of 10 mV s⁻¹ and (b) change in specific capacitance as a function of the NiCl₂·6H₂O to trypan blue ratios for Try-Ni-MOF/NF electrodes.

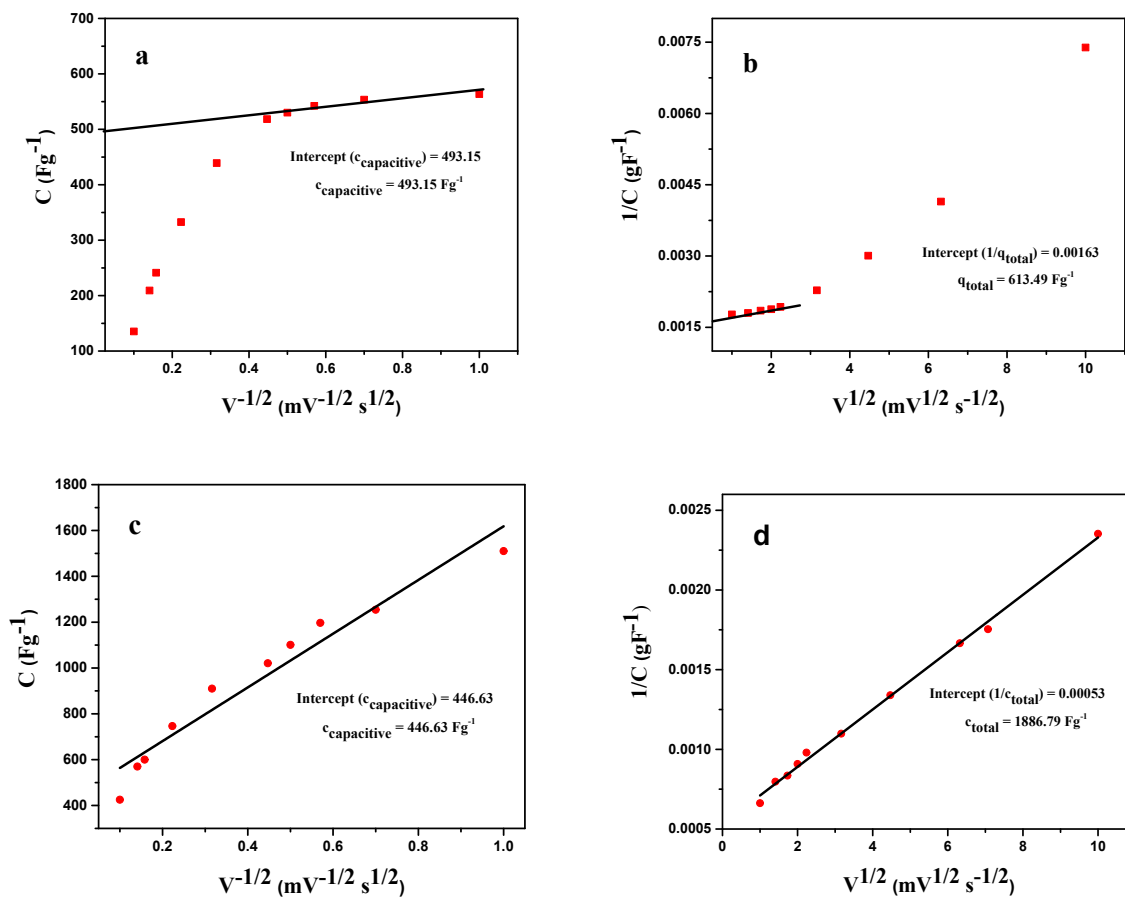


Fig. S14. (a and c) the voltammetric charge (c) versus scan rate ($v^{-1/2}$) and (b and d) $1/c(v)$ versus $v^{1/2}$ plots for Az-GA/NF and Try-Ni-MOF/NF electrode, according to Trasatti method.

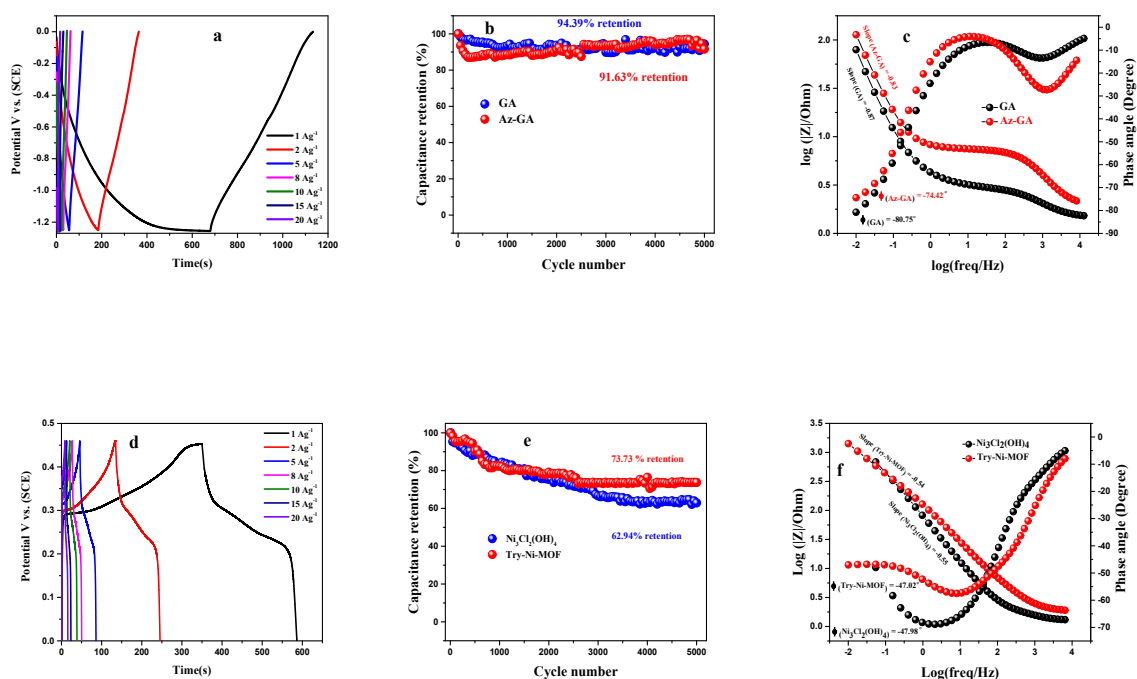
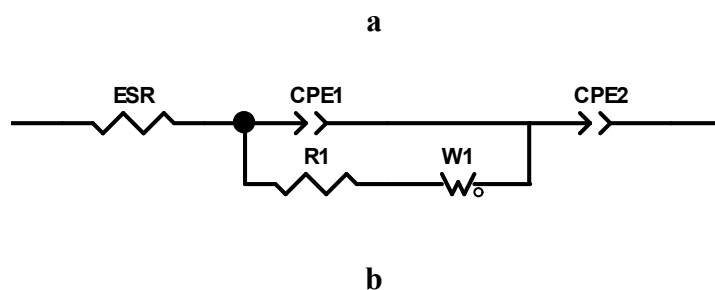


Fig. S15. (a, d) GCD of the GA/NF and $\text{Ni}_3\text{Cl}_2(\text{OH})_4/\text{NF}$ electrodes at different current densities in an aqueous 3.0 M KOH electrolyte, (b, e) long-term cycling stability of the GA/NF, Az-GA/NF, $\text{Ni}_3\text{Cl}_2(\text{OH})_4/\text{NF}$, and Try-Ni-MOF/NF electrodes over 5000 cycles at a current density of 10 A g^{-1} in an aqueous 3.0 M KOH electrolyte, and (c, f) Bode plots ($\log |Z|$ vs. \log frequency and phase angle vs. \log frequency) for the GA/NF, Az-GA/NF, $\text{Ni}_3\text{Cl}_2(\text{OH})_4/\text{NF}$, and Try-Ni-MOF/NF electrodes at a frequency range from 100 KHz to 10 mHz, respectively.



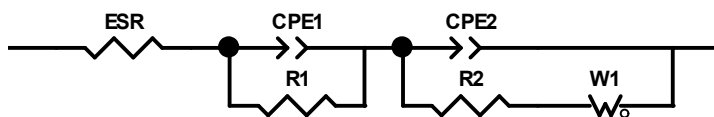


Fig. S16. Equivalent circuit models used to fit the experimental EIS data of the (a) GA/NF and Az-GA/NF and (b) $\text{Ni}_3\text{Cl}_2(\text{OH})_4/\text{NF}$ and Try-Ni-MOF/NF electrodes in a three-electrode system and in an aqueous 3.0 M KOH electrolyte, respectively.

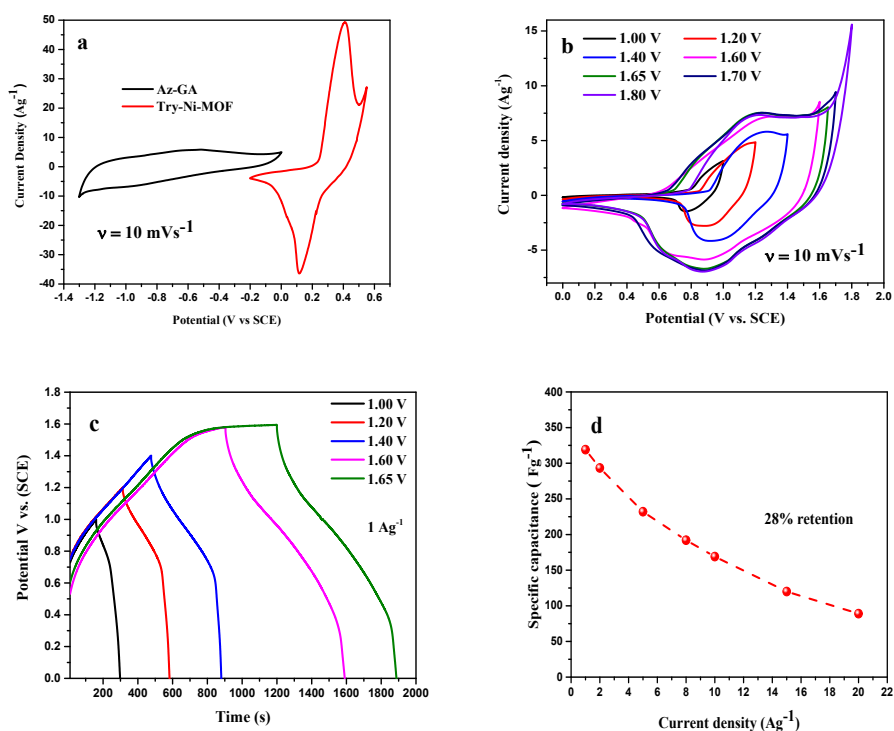


Fig. S17. (a) Az-GA (negative pole) and Try-Ni-MOF (positive pole) electrodes measured at a scan rate of 10 mV s^{-1} in three-electrode configurations, (b) CV curves of the Az-GA//Try-Ni-MOF asymmetric device at different potential windows 10 mV s^{-1} , (c) GCDs of a Az-GA//Try-Ni-MOF asymmetric device at different potential windows, and (d) specific capacitances of Az-GA//Try-Ni-MOF asymmetric device at various current densities.

Table S1 The d-spacing and crystallite size of GO, GA, Az-GA, Ni₃Cl₂(OH)₄, and Try-Ni-MOF.

Dataset Name	Pos. [θ]	Height [cts]	FWHM Left [θ .]	d-spacing [\AA]	d- mean size [nm]
GO	11.36(9)	2688.85	1.200	7.84613	-
GA	24.36(2)	2056.6	0.64	3.65065	-
Az-GA	26.41(1)	585.0	0.7230	3.38550	-
Ni ₃ Cl ₂ (OH) ₄	12.8784	7976.82	0.3936	6.87422	5-11
Try-Ni-MOF	11.588(9)	1184(16)	2.79(2)	7.63027	2-5

Table S2. Comparison of the electrochemical performances of the Az-GA electrode with other anode electrode reported literatures.

Electrode material	Areal capacitance/capacity (F cm ⁻² /mA h cm ⁻²)	Specific capacitance/capacity (F g ⁻¹ /mA h g ⁻¹)	Current load	Electrolyte	Stability (Cycles)	Ref.
NiCo₂O₄/GH/NF composite	3.84 F cm ⁻²	3428 F g ⁻¹	2 mA cm ⁻²	0.008 M NiCl ₂ .6H ₂ O, 0.016 M CoCl ₂ .6H ₂ O, and 0.1 M Na ₂ SO ₄	-	1
FGS^a-SSG^b/PANI	1.36 F cm ⁻²	491.3 F g ⁻¹	0.5 A g ⁻¹	1.0 M H ₂ SO ₄	86% at 50 mVs ⁻¹ (3,000)	2
Fe₃O₄/graphene nanocomposites	-	300 F g ⁻¹	0.4 A g ⁻¹	1.0 M KOH	93% at 0.4 A g ⁻¹ (500 cycles)	3
SG^c/PANI	-	478 F g ⁻¹	0.5 A g ⁻¹	1.0 M H ₂ SO ₄	88% at	4

nanocomposite papers					0.5 A g ⁻¹ (2,000)	
Th–GA^d nanocomposite	-	512 F g ⁻¹	1 A g ⁻¹	1.0 M H ₂ SO ₄	82% at 1 A g ⁻¹ (6,000)	5
Graphene encapsulated NiS/Ni₃S₄ (NSG) nanostructure	-	827 F g ⁻¹	5 A g ⁻¹	6.0 M KOH	88% at 5 A g ⁻¹ (5,000)	6
3-D GPCN nanosheets^e	-	316.8 F g ⁻¹	1 A g ⁻¹	1.0 M KOH	92.5% at 1 A g ⁻¹ (2,000)	7
MnO₂/VGNs^f/Ni hybrid	186 mFcm ⁻²	-	1 mA cm ⁻²	0.1 M MnSO ₄ and 1 M Na ₂ SO ₄	60% at 100 mVs ⁻¹ (10,000)	8
RGO/Ni₃S₂/MoS₂ composite	6451 mF·cm ⁻²	-	40 mA·cm ⁻²	2.0 M KOH	87.2% at 110 mA·cm ⁻² (5,000)	9
NiFe/rGO	-	1224 F g ⁻¹	10 mVs ⁻¹	1.0 M KOH	89% at 10 mVs ⁻¹ (2,000)	10
GA^g@NF	-	366 F g ⁻¹	2 A g ⁻¹	6.0 M KOH	60% at 10 A g ⁻¹ (2,000)	11
Az-GA	-	716.06 F g ⁻¹	1 A g ⁻¹	3.0 M KOH	94.39% at 10 A g ⁻¹ (5,000)	This work

^a FGS : Flexible graphite sheet, ^b SSG : Self-supporting graphene, ^c SG :Sulfonate graphene, ^d Th–GA : Thionine–Graphene aerogel, ^e 3-D GPCN nanosheets : Three-dimensional graphene-like porous carbon nanosheets, ^f VGNs : Vertical graphene nanosheets, ^g GA : Graphene aerogel

Table S3. Comparison of the electrochemical performances of the Try-Ni-MOF electrode with other cathode electrode reported literatures.

Electrode material	Areal capacitance / capacity (F cm ⁻² /mA h cm ⁻²)	Specific capacitance / capacity (F g ⁻¹ /mA h g ⁻¹)	Current load	Electrolyte	Stability (Cycles)	Ref.
Ni_{4.5}Co_{4.5}S₈ (Ni battery)	-	206 mAh g ⁻¹	1 A g ⁻¹	4.0 M KOH	95% at 20 A g ⁻¹ (5,000)	12
Ni(OH)₂/NG^a (Ni battery)		230 mAh g ⁻¹	1 A g ⁻¹	1.0 M KOH	93% at 10 mV ⁻¹ (1,000)	13
LiNi_{0.5}Mn_{1.5}O₄ (Li-ion battery)	-	144 mAh g ⁻¹	150 mA g ⁻¹	LiPF ₆ in Ethylene carbonate and dimethyl carbonate	90% at 300 mA g ⁻¹ (250)	14
Ni-MH (Ni battery)	-	276 mAh g ⁻¹	0.1 C (1 C=183.6 mA g ⁻¹)	PVA/ KOH	-	15
NiO@Ni Micro/nanostructures	92.4 mF cm ⁻²	-	1 mA cm ⁻²	2.0 M KOH	100% at 4 A g ⁻¹ (1,500)	16
NiO/CuO_{-0.3}/GO₋₃₀ composites	-	1451 F g ⁻¹	1 A g ⁻¹	6.0 M KOH	82.95% at 10 A g ⁻¹ (1,000)	17
(Co(OH)₂/Co₉S₈) @ NiTe/Ni composite	5.28 F cm ⁻²	-	10 mA cm ⁻²	6.0 M KOH	87.80% at 50 A g ⁻¹ (10,000)	18
Ni-Co-S/NF nanosheet	-	1406.9 F g ⁻¹	0.5 A g ⁻¹	1.0 M KOH	88.6% at 10 A g ⁻¹ (1,000)	19
NiO	-	523 F g ⁻¹	1 A g ⁻¹	6.0 M KOH	77.25% at 10 A g ⁻¹ (1,000)	17
Co²⁺/Co³⁺- doped Ni(OH)₂ branched	-	999 F g ⁻¹	2 A g ⁻¹	3.0 M	82% at	20

nanosheets-interlaced structure				KOH	10 A g ⁻¹ (7,000)	
2D N-NiO UTNSs^b	-	540 F g ⁻¹	1 A g ⁻¹	1.0 M KOH	85% at 10 A g ⁻¹ (10,000)	²¹
NiCoP/NPC HFSs^c composite	-	660.3 F g ⁻¹	1 A g ⁻¹	3.0 M KOH	85% at 6 A g ⁻¹ (2,000)	²²
Try-Ni-MOF	-	845.43 F g ⁻¹	1 A g ⁻¹	3.0 M KOH	73.73% at 10 A g ⁻¹ (5,000)	This work

^a NG : Nitrogen-doped graphene, ^b 2D N-NiO UTNSs : 2D N-doped NiO ultrathin nanosheets, ^c NPC HFSs: N and P atoms with hollow and fold-sphere, ^e :

Table S4. Values of equivalent circuit parameters for the GA and Az-GA electrodes

Sample	ESR (Ω)	R _{ct1} (Ω)	CPE ₁ (Fs ⁿ⁻¹)	n ₁	W (Ω s ^{-1/2})	CPE ₂ (Fs ⁿ⁻¹)	n ₂
GA	1.45	1.44	1.4 × 10 ⁻³	0.75	0.27	0.26	0.92
Az-GA	1.87	5.50	0.27 × 10 ⁻³	0.81	0.32	0.11	0.90

Table S5. Values of equivalent circuit parameters for the Ni₃Cl₂(OH)₄ and Try-Ni-MOF electrodes

Sample	ESR (Ω)	R _{ct1} (Ω)	CPE ₁ (Fs ⁿ⁻¹)	n ₁	W (Ω s ^{-1/2})	R _{ct2} (Ω)	CPE ₂ (Fs ⁿ⁻¹)	n ₂
Ni ₃ Cl ₂ (OH) ₄	1.27	0.31	1.3 × 10 ⁻³	0.80	1.02	1336	2.7 × 10 ⁻³	0.80
Try-Ni-MOF	1.78	1.58	2.5 × 10 ⁻³	0.82	0.50	248	1.5 × 10 ⁻³	0.75

Table S6. Comparison of the electrochemical performances of the Az-GA//Try-Ni-MOF device with other devices.

Device (Type)	Capacity (mAh g ⁻¹)	Capacitance (F g ⁻¹)	Specific energy (Wh kg ⁻¹) at specific power (kW kg ⁻¹)	Specific power (kW kg ⁻¹) at specific energy (Wh kg ⁻¹)	Cycles	Capacity retention	Electrolyte	Ref.
ZCNM-NS ^a //AC ^b (battery- supercapacitor hybrid)	-	71.3 at 5 mA cm ⁻²	25.3 at 0.787	9.4 at 18.4	5,000	81.5% at 10 mA cm ⁻²	2.0 M KOH	23
rG/NCS/NCO ^c //rGO (Asym. supercapacitor)	-	104 at 3 A g ⁻¹	32 at 0.375	-	1,000	82 % at 30 A g ⁻¹	PVA-KOH	24
Co(OH) ₂ -MoSe ₂ //AC (Asym. supercapacitor)	-	99 at 1 A g ⁻¹	30.12 at 0.985	12.2 at 18.28	3,000	86.2% at 10 A g ⁻¹	6.0 M KOH	25
ZnFe ₂ O ₄ //Ni(OH) ₂ (Asym. supercapacitor)	-	93 at 0.6 mA cm ⁻²	33 at 0.068	0.209 at 14	1,000	88% at 1 mA cm ²	6.0 M KOH	26
Pd-GA//Ni(OH) ₂ (Ni superbattery)	190 at 0.2 A g ⁻¹	429 at 0.2 A g ⁻¹	185.7 at 38.8 × 10 ⁻³	11.3 at 30.3	1,000	54% at 4 A g ⁻¹	6.0 M KOH	27
PCO//3DPG (pseudocapacitive)	-	229 at 2 A g ⁻¹	71.58 at 1.5	-	2000	95% at 50 mV s ⁻¹	6.0 M KOH	28
AC//LiNi _{0.5} Mn _{1.5} O ₄ (Li-ion capacitor)	-	124 at 100 mA g ⁻¹	19 at 0.150	2.5 at 8.0	3,000	81% at 1 A g ⁻¹	1.0 M LiPF ₆	14
NiCoMoS _x //AC (Asym. Supercapacitor)	-	136 at 1 A g ⁻¹	48.2 at 0.807	-	10,000	91.6% at 1 A g ⁻¹	3.0 M KOH	29

CoNi-MOF//AC (Asym. Supercapacitor)	-	-	28.5 at 1.5	-	5,000	94% at 1 A g ⁻¹	1.0 M KOH	30
HCO-PFC^d//FG^f full cell	1960 at 3 mA cm ⁻²	1633 at 3 mA cm ⁻²	79.54 at 0.778	-	5,000	81% at 20 A g ⁻¹	6 m KOH + 0.06 m PFC	31
GON^e//RGO (Asym. Supercapacitor)	-	-	40.5 at 0.900	8.526 at 9.5	5,000	87% at 10 A g ⁻¹	PVA/KOH	32
Fe₃C/CF//Ni_{4.5}Co_{4.5}- selenide nanowires/NPCC (Battery- supercapacitor)	-	113.7 at 1 A g ⁻¹	47.4 at 1.5	-	4,000	80% at 10 A g ⁻¹	PVA/KOH	33
Ni₃S₂/NiV- LDH/rGO/NF//AC (Asym. Supercapacitor)	-	-	59.4 at 0.852	-	8,000	98.3% at 2 A g ⁻¹	2.0 M KOH	34
Cd-GA//Ni(OH)₂ (Ni superbattery)	50 at 0.15 A g ⁻¹	-	51.7 at 100 mA g ⁻¹	5.4 at 7.8	1,000	88% at 6 A g ⁻¹	6.0 M KOH	27
GM-LEG^g @NiCo- MOF//AC	-	3250 at 7.5 A g ⁻¹	76.3 at 2.25	-	-	-	3.0 M KOH + 0.1 M K ₄ [Fe(CN) ₆]	35
Az-GA//Try-Ni-MOF (Asym. supercapatteries)	-	319 at 1 A g ⁻¹	66.55 at 0.349	4.5 at 11.11	5,000	92.12% at 10 A g ⁻¹	3.0 M KOH	This work

^a ZCNM-NS : ZnCo₂O₄@NiMoO₄ core-shell nanosheets, ^b AC: activated carbon, ^c NCS/NCO: NiCo₂S₄@NiCo₂O₄ core@shell nanoneedle, ^d PFC : potassium ferricyanide, ^f FG: Fe₂O₃/graphene, ^e GON: nitrogen grafted graphene oxinitride, ^g LEG : liquid-phase exfoliated graphene

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